

DATASHEET

8 PIN DIP HIGH SPEED 10MBit/s LOGIC GATE PHOTOCOUPLER 6N137 EL26XX series



Features

- High speed 10Mbit/s
- 10kV/µs min. common mode transient immunity (EL2611)
- Guaranteed performance from -40 to 85°C
- · Logic gate output
- High isolation voltage between input and output (Viso=5000 V rms)
- Pb free and RoHS compliant.
- UL and cUL approved(No. E214129)
- VDE approved (No. 132249)
- SEMKO approved
- NEMKO approved
- DEMKO approved
- FIMKO approved

Schematic 1 8 7

A 0.1µF bypass capacitor must be connected between pins 8 and 5 *3

5

Pin Configuration

- 1. No Connection
- 2, Anode
- 3, Cathode
- 4. No Connection
- 5, Gnd
- 6, Vout
- $7, V_{E}$
- $8,\,V_{CC}$

Description

The 6N137, EL2601 and EL2611 are consists of an infrared emitting diode optically coupled to a high speed integrated photo detector logic gate with a strobable output. It is packaged in a 8-pin DIP package and available in wide-lead spacing and SMD options.

Applications

- Ground loop elimination
- LSTTL to TTL, LSTTL or 5 volt CMOS
- Line receiver, data transmission
- Data multiplexing
- Switching power supplies
- Pulse transformer replacement
- Computer peripheral interface
- High speed logic ground isolation

Truth Table (Positive Logic)

Input	Enable	Output
Н	Н	L
L	Н	Н
Н	L	Н
L	L	Н
Н	NC	L
L	NC	Н



Absolute Maximum Ratings (Ta=25°C)

	Parameter	Symbol	Rating	Unit
	Forward current	l _F	50	mA
Input	Enable input voltage Not exceed V _{CC} by more than 500mV	VE	5.5	V
mpat	Reverse voltage	V_{R}	5	V
	Power dissipation	P _D	100	mW
	Power dissipation	Pc	85	mW
0	Output current	lo	50	mA
Output	Output voltage	Vo	7.0	V
	Supply voltage	Vcc	7.0	V
Output Po	ower Dissipation	Po	100	mW
Isolation v	voltage ^{*1}	V _{ISO}	5000	V rms
Operating temperature		T _{OPR}	-40 ~ +85	°C
Storage temperature		T _{STG}	-55 ~ +125	°C
Soldering	temperature *2	T _{SOL}	260	°C

Notes:

^{*1} AC for 1 minute, R.H.= 40 ~ 60% R.H. In this test, pins 1, 2, 3 & 4 are shorted together, and pins 5, 6, 7 & 8 are shorted together.

^{*2} For 10 seconds.



Electrical Characteristics (Ta=-40 to 85°C unless specified otherwise)

Input

Parameter	Symbol	Min.	Тур.	Max.	Unit	Condition
Forward voltage	V_{F}	-	1.4	1.8	V	$I_F = 10mA$
Reverse voltage	V_{R}	5.0	-	-	V	$I_R = 10\mu A$
Temperature coefficient of forward voltage	$\Delta V_F/\Delta T_A$	-	-1.8	-	mV/°C	I _F =10mA
Input capacitance	C _{IN}	-	60	-	pF	V _F =0, f=1MHz

Output

Parameter	Symbol	Min	Тур.	Max.	Unit	Condition
High level supply current	Іссн	-	7	10	mA	$I_F=0$ mA, $V_E=0.5$ V, $V_{CC}=5.5$ V
Low level supply current	Iccl	-	9	13	mA	I _F =10mA, V _{CC} =5.5V
High level enable current	I _{EH}	-	- 0.6	-1.6	mA	V _E =2.0 V, V _{CC} =5.5V
Low level enable current	I _{EL}	-	- 0.8	-1.6	mA	V _E =0.5 V, V _{CC} =5.5V
High level enable voltage	V _{ЕН}	2.0	1 -1		V	I _F =10mA, V _{CC} =5.5V
Low level enable voltage*4	V_{EL}	14		0.8	V	$I_F=10mA$, $V_{CC}=5.5V$

Transfer Characteristics (Ta=-40 to 85°C unless specified otherwise)

Parameter	Symbol	Min	Тур.	Max.	Unit	Condition
HIGH Level Output Current	Іон	-	2.1	100	uA	V _{CC} =5.5V, V _O =5.5V, I _F =250μA, V _E =2.0V
LOW Level Output Current	VoL	-	0.35	0.6	V	$V_{CC} = 5.5V$, $I_F=5mA$, $V_E=2.0V$, $I_{CL}=13mA$
Input Threshold Current	I _{FT}	-	2.5	5	mA	V _{CC} = 5.5V, V _O =0.6V, V _E =2.0V,I _O L=13mA



Switching Characteristics (Ta=-40 to 85°C, Vcc=5V, IF=7.5mA unless specified otherwise)

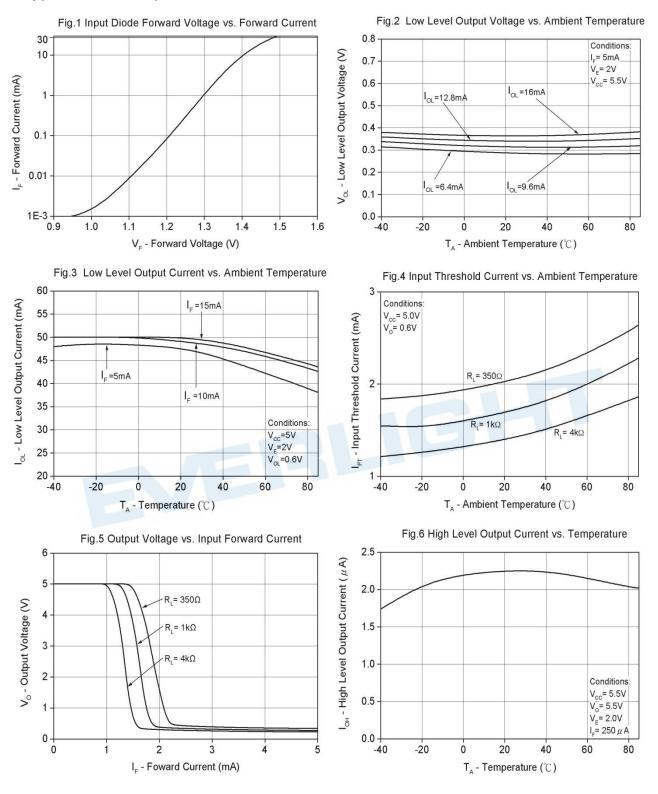
Parameter	Symbol	Min	Тур.	Max.	Unit	Condition
Propagation delay time to output High level*5 (Fig.12)	T_{PHL}	-	35	75	ns	C_L = 15pF, R_L =350 Ω , T_A =25°C
Propagation delay time to output Low level*6 (Fig.12)	T _{PLH}	-	40	75	ns	C_L = 15pF, R_L =350 Ω , T_A =25°C
Pulse width distortion	Tphl – Tplh	-	5	35	ns	$C_L = 15pF, R_L = 350\Omega$
Output rise time* ⁷ (Fig.12)	tr	-	40	-	ns	C _L = 15pF, R _L =350Ω
Output fall time*8 (Fig.12)	tf	-	10	-	ns	C _L = 15pF, R _L =350Ω

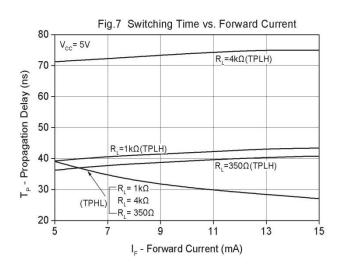
Switching Characteristics (Ta=-40 to 85°C, Vcc=5V, IF=7.5mA unless specified otherwise)

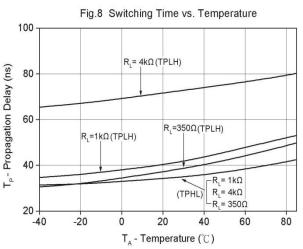
Param	eter	Symbol	Min	Тур.	Max.	Unit	Condition
Enable Propa Delay Time to High Level*9 (Fig.13)	Output	t _{ELH}	-	15	-	ns	I_F = 7.5mA , V_{EH} = 3.5V, C_L = 15pF, R_L = 350 Ω
Enable Propa Delay Time to Low Level*10 (Fig.13)		t _{EHL}		15	C	ns	$I_F = 7.5 \text{mA} , V_{EH} = 3.5 \text{V},$ $C_L = 15 \text{pF}, R_L = 350 \Omega$
	6N137	Æ	K		-		I_F = 0mA , V_{OH} =2.0V, R_L =350 Ω , T_A =25°C V_{CM} =10Vp-p (Fig.14)
Common Mode Transient	EL2601	- СМ _Н	5,000	-	-	V/µS	$\begin{split} I_F &= 0\text{mA} \text{ , } V_{\text{OH}} = 2.0\text{V}, \\ R_L &= 350\Omega, T_{\text{A}} = 25^{\circ}\text{C} \\ V_{\text{CM}} &= 50\text{Vp-p (Fig.14)} \end{split}$
Immunity at Logic High *11	EL2611		10,000	-	-	ν/μ3	$\begin{split} I_F &= 0 \text{mA} \text{ , } V_{OH} = 2.0 \text{V}, \\ R_L &= 350 \Omega \text{, } T_A = 25 ^{\circ} \text{C} \\ V_{CM} &= 400 \text{Vp-p (Fig.14)} \end{split}$
	EL2611		20,000	-	-		$\begin{split} I_F &= 0 \text{mA} \text{ , } V_{OH} = 2.0 \text{V}, \\ R_L &= 350 \Omega \text{, } T_A = 25 ^{\circ} \text{C} \\ V_{CM} &= 400 \text{Vp-p (Fig.15)} \end{split}$
	6N137	_	-	-	-		$\begin{array}{c} \text{I}_{\text{F}} = 7.5 \text{mA} \text{ , V}_{\text{OL}} = 0.8 \text{V}, \\ \text{R}_{\text{L}} = 350 \Omega \text{, T}_{\text{A}} = 25 ^{\circ} \text{C} \\ \text{V}_{\text{CM}} = 10 \text{Vp-p (Fig.14)} \end{array}$
Common Mode Transient Immunity at Logic Low *12	EL2601	- CM _L	5,000	-	-	V/µS	I_F = 7.5mA , V_{OL} = 0.8V, R_L = 350 Ω , T_A = 25°C V_{CM} = 50Vp-p (Fig.14)
	EL2611	- Olvic	10,000	-	-	ν/μΟ	$I_F = 7.5 mA , V_{OL} = 0.8 V, \\ R_L = 350 \Omega, T_A = 25 ^{\circ} C \\ V_{CM} = 400 Vp-p \ (Fig.14)$
	EL2611		20,000	-	-		$I_F=7.5\text{mA} \ , \ V_{OH}=0.8\text{V}, \\ R_L=350\Omega, \ T_A=25^{\circ}\text{C} \\ V_{CM}=400\text{Vp-p} \ (\text{Fig.15})$

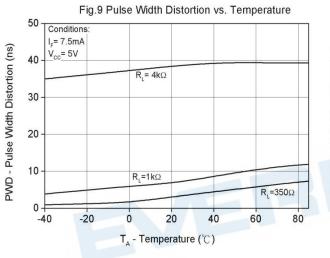


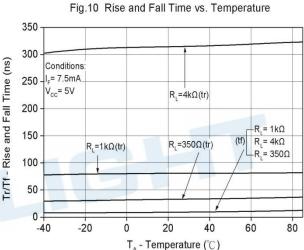
Typical Electro-Optical Characteristics Curves











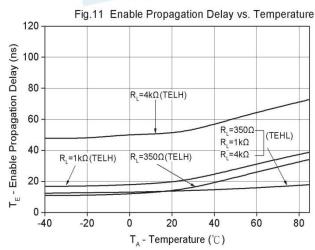




Fig. 12 Test circuit and waveforms for tPHL, tPLH, tr, and tf

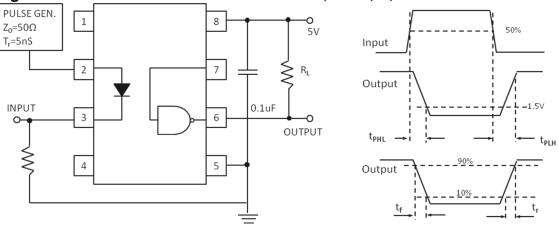


Fig. 13 Test circuit and waveform for tehland telh

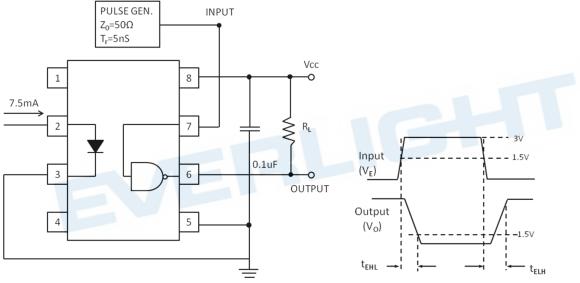


Fig. 14 Test circuit Common mode Transient Immunity

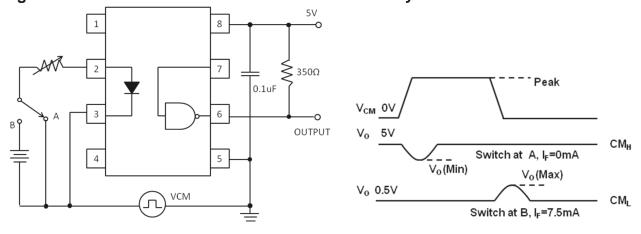
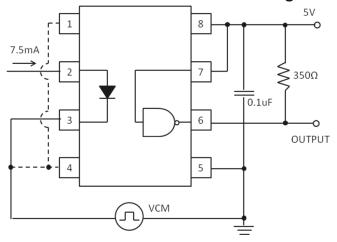




Fig. 15 Recommended drive circuit for EL2611 families for high-CMR



Note

- *3 The VCC supply must be bypassed by a 0.1µF capacitor or larger. This can be either a ceramic or solid tantalum capacitor with good high frequency characteristic and should be connected as close as possible to the package VCC and GND pins
- *4. Enable Input No pull up resistor required as the device has an internal pull up resistor.
- *5. tPLH Propagation delay is measured from the 3.75mA level on the HIGH to LOW transition of the input current pulse to the 1.5 V level on the LOW to HIGH transition of the output voltage pulse.
- *6. tPHL Propagation delay is measured from the 3.75mA level on the LOW to HIGH transition of the input current pulse to the 1.5 V level on the HIGH to LOW transition of the output voltage pulse.
- *7. tr Rise time is measured from the 90% to the 10% levels on the LOW to HIGH transition of the output pulse.
- *8. tf Fall time is measured from the 10% to the 90% levels on the HIGH to LOW transition of the output pulse.
- *9. tELH Enable input propagation delay is measured from the 1.5V level on the HIGH to LOW transition of the input voltage pulse to the 1.5V level on the LOW to HIGH transition of the output voltage pulse.
- *10. tEHL Enable input propagation delay is measured from the 1.5V level on the LOW to HIGH transition of the input voltage pulse to the 1.5V level on the HIGH to LOW transition of the output voltage pulse.
- *11 CMH– The maximum tolerable rate of rise of the common mode voltage to ensure the output will remain in the HIGH state (i.e., VOUT > 2.0V).
- *12 CML— The maximum tolerable rate of rise of the common mode voltage to ensure the output will remain in the LOW output state (i.e., VOUT < 0.8V).



Order Information

Part Number

6N137Y(Z)-V

or

EL26XXY(Z)-V

Note

X Y = (01 or 11) for EL26 part no.

= Lead form option (S, S1, M or none)

Z V = Tape and reel option (TA, TB or none).

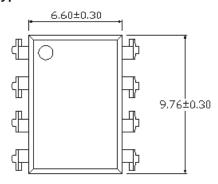
= VDE (optional)

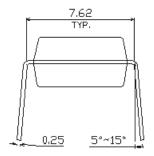
None S		Packing quantity
	Standard DIP-8	45 units per tube
M V	Wide lead bend (0.4 inch spacing)	45 units per tube
S (TA)	Surface mount lead form + TA tape & reel option	1000 units per reel
S (TB)	Surface mount lead form + TB tape & reel option	1000 units per reel
S1 (TA)	Surface mount lead form (low profile) + TA tape & reel option	1000 units per reel
S1 (TB)	Surface mount lead form (low profile) + TB tape & reel option	1000 units per reel

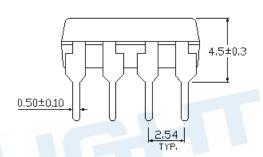


Package Dimension (Dimensions in mm)

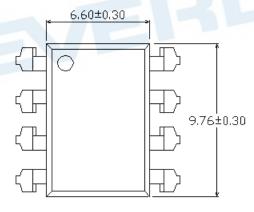
Standard DIP Type

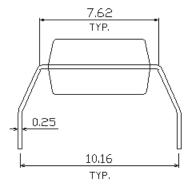


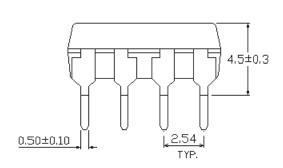




Option M Type

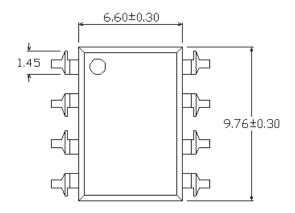


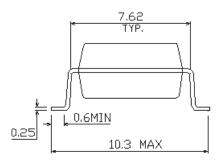


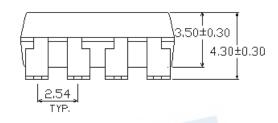




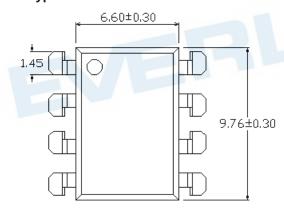
Option S Type

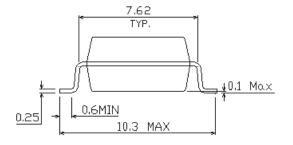


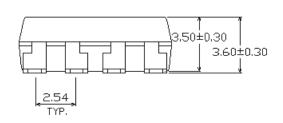




Option S1 Type

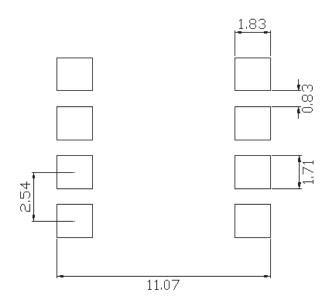








Recommended pad layout for surface mount leadform

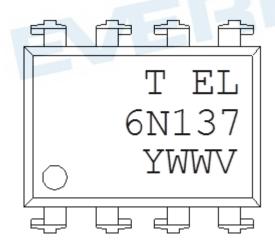


Notes.

Suggested pad dimension is just for reference only.

Please modify the pad dimension based on individual need.

Device Marking



Notes

T denotes Factory

No code : made in China

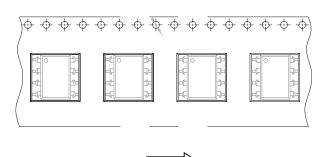
T : made in Taiwan

EL denotes EVERLIGHT
6N137 denotes Device Number
Y denotes 1 digit Year code
WW denotes 2 digit Week code
V denotes VDE (optional)



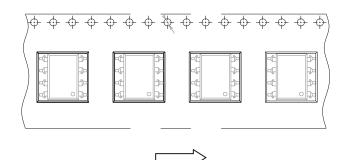
Tape & Reel Packing Specifications

Option TA



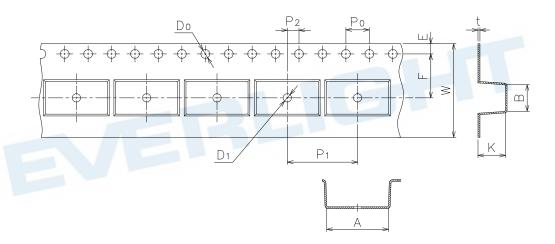
Direction of feed from reel

Option TB



Direction of feed from reel

Tape dimension



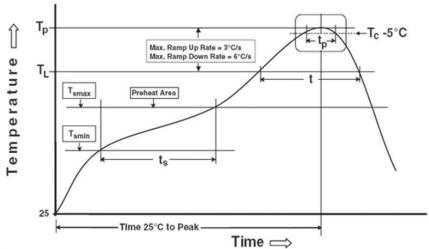
Dimension No.	Α	В	Do	D1	E	F
Dimension(mm)	10.4±0.1	10.0±0.1	1.5+0.1-0	1.5±0.25	1.75±0.1	7.5±0.1
Dimension No.	Ро	P1	P2	t	W	К
Dimension(mm)	4.0±0.1	12.0±0.1	2.0±0.05	0.4±0.05	16.0±0.3	4.5±0.1



Precautions for Use

1. Soldering Condition

1.1 (A) Maximum Body Case Temperature Profile for evaluation of Reflow Profile



Note: Reference: IPC/JEDEC J-STD-020D

Preheat

Temperature min (T_{smin}) 150 °C

Temperature max (T_{smax}) 200°C

Time $(T_{smin} \text{ to } T_{smax})$ (t_s) 60-120 seconds

Average ramp-up rate $(T_{smax} \text{ to } T_p)$ 3 °C/second max

Other

Other	
Liquidus Temperature (T _L)	217 °C
Time above Liquidus Temperature (t L)	60-100 sec
Peak Temperature (T _P)	260°C
Time within 5 °C of Actual Peak Temperature: T _P - 5°C	30 s
Ramp- Down Rate from Peak Temperature	6°C /second max.
Time 25°C to peak temperature Reflow times	8 minutes max. 3 times



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